



CYPRESS

**CY7C1328A/GVT71256F18**

**CY7C1348A/GVT71128F36**

## **128K x 36/256K x 18 Synchronous-Pipelined Cache RAM**

### **Features**

- **Fast access times: 3.5, 3.8, and 4.0 ns**
- **Fast clock speed: 166, 150, 133, and 117 MHz**
- **Provide high performance 3-1-1-1 access rate**
- **Fast OE access times: 3.5 ns and 3.8 ns**
- **Optimal for performance (double cycle chip deselect, depth expansion without wait state)**
- **3.3V -5% and +10% core power supply**
- **2.5V or 3.3V I/O supply**
- **5V tolerant inputs except I/Os**
- **Clamp diodes to V<sub>SSQ</sub> at all inputs and outputs**
- **Common data inputs and data outputs**
- **Byte Write Enable and Global Write control**
- **Three chip enables for depth expansion and address pipeline**
- **Address, data and control registers**
- **Internally self-timed Write Cycle**
- **Burst control pins (interleaved or linear burst sequence)**
- **Automatic power-down for portable applications**
- **High-density, high-speed packages**

### **Functional Description**

The Cypress Synchronous Burst SRAM family employs high-speed, low-power CMOS designs using advanced triple-layer polysilicon, double-layer metal technology. Each memory cell consists of four transistors and two high-valued resistors.

The CY7C1348A/GVT71128F36 and CY7C1328A/GVT71256F18 SRAM integrate 262,144x18 and 131,072x36 SRAM cells with advanced synchronous peripheral circuitry.

### **Selection Guide**

|                                   | <b>7C1328A-166<br/>71256F18-3<br/>7C1348A-166<br/>71128F36-3</b> | <b>7C1328A-150<br/>71256F18-4<br/>7C1348A-150<br/>71128F36-4</b> | <b>7C1328A-133<br/>71256F18-5<br/>7C1348A-133<br/>71128F36-5</b> | <b>7C1328A-117<br/>71256F18-6<br/>7C1348A-117<br/>71128F36-6</b> |
|-----------------------------------|--|--|--|--|
| Maximum Access Time (ns)          | 3.5  | 3.8  | 4.0  | 4.0  |
| Maximum Operating Current (mA)    | 425  | 400  | 375  | 350  |
| Maximum CMOS Standby Current (mA) | 10   | 10   | 10   | 10   |

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PowerPC is a trademark of International Business Machines, Incorporated.

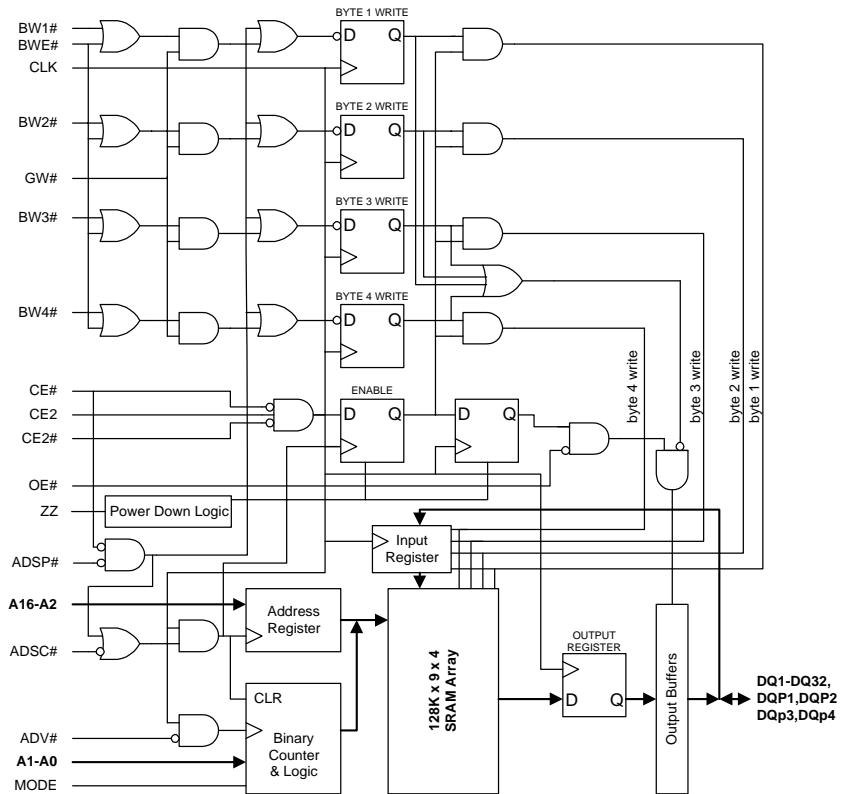
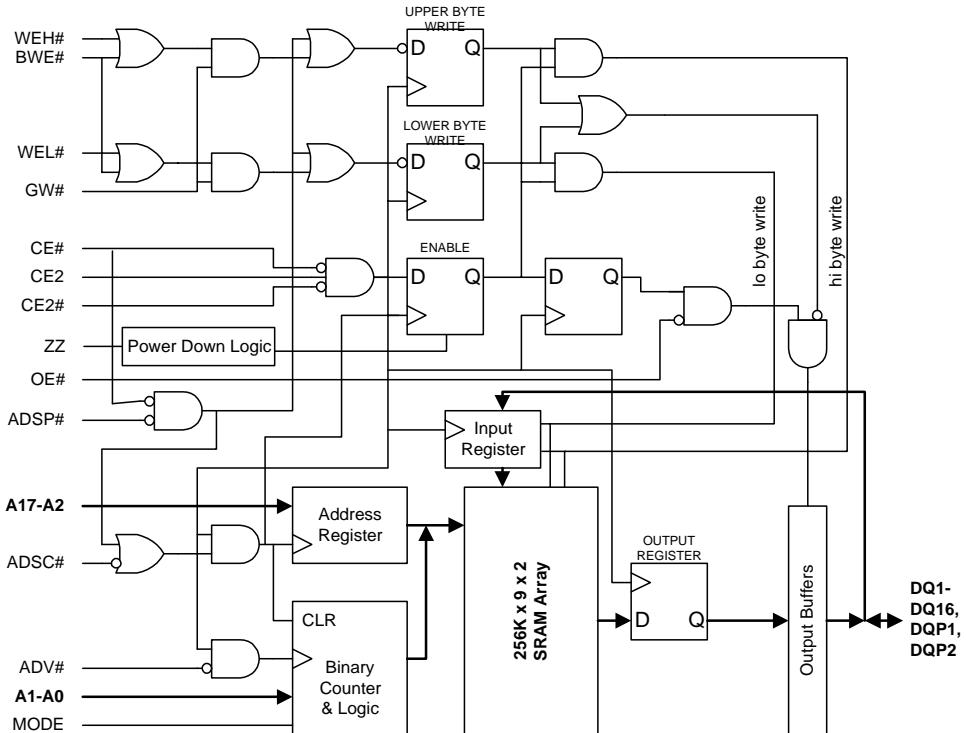
and a 2-bit counter for internal burst operation. All synchronous inputs are gated by registers controlled by a positive-edge-triggered Clock Input (CLK). The synchronous inputs include all addresses, all data inputs, address-pipelining Chip Enable (CE), depth-expansion Chip Enables (CE2 and CE2), Burst Control inputs (ADSC, ADSP, and ADV), Write Enables (BW1, BW2, BW3, BW4, and BWE), and Global Write (GW).

Asynchronous inputs include the Output Enable ( $\overline{OE}$ ) and Burst Mode Control (MODE). The data outputs (Q), enabled by  $\overline{OE}$ , are also asynchronous.

Addresses and chip enables are registered with either Address Status Processor (ADSP) or Address Status Controller (ADSC) input pins. Subsequent burst addresses can be internally generated as controlled by the Burst Advance pin (ADV).

Address, data inputs, and write controls are registered on-chip to initiate self-timed WRITE cycle. WRITE cycles can be one to four bytes wide as controlled by the write control inputs. Individual byte write allows individual byte to be written. BW1 controls DQ1–DQ8 and DQP1. BW2 controls DQ9–DQ16 and DQP2. BW3 controls DQ17–DQ24 and DQP3. BW4 controls DQ25–DQ32 and DQP4. BW1, BW2, BW3, and BW4 can be active only with BWE being LOW. GW being LOW causes all bytes to be written. WRITE pass-through capability allows written data available at the output for the immediately next READ cycle. This device also incorporates pipelined enable circuit for easy depth expansion without penalizing system performance.

The CY7C1348A/GVT71128F36/CY7C1328A/GVT71256F18 operates from a +3.3V core power supply and all outputs operate on a +2.5V supply. All inputs and outputs are JEDEC standard JESD8-5 compatible. The device is ideally suited for 486, Pentium®, 680x0, and PowerPC™ systems and for systems that benefit from a wide synchronous data bus.

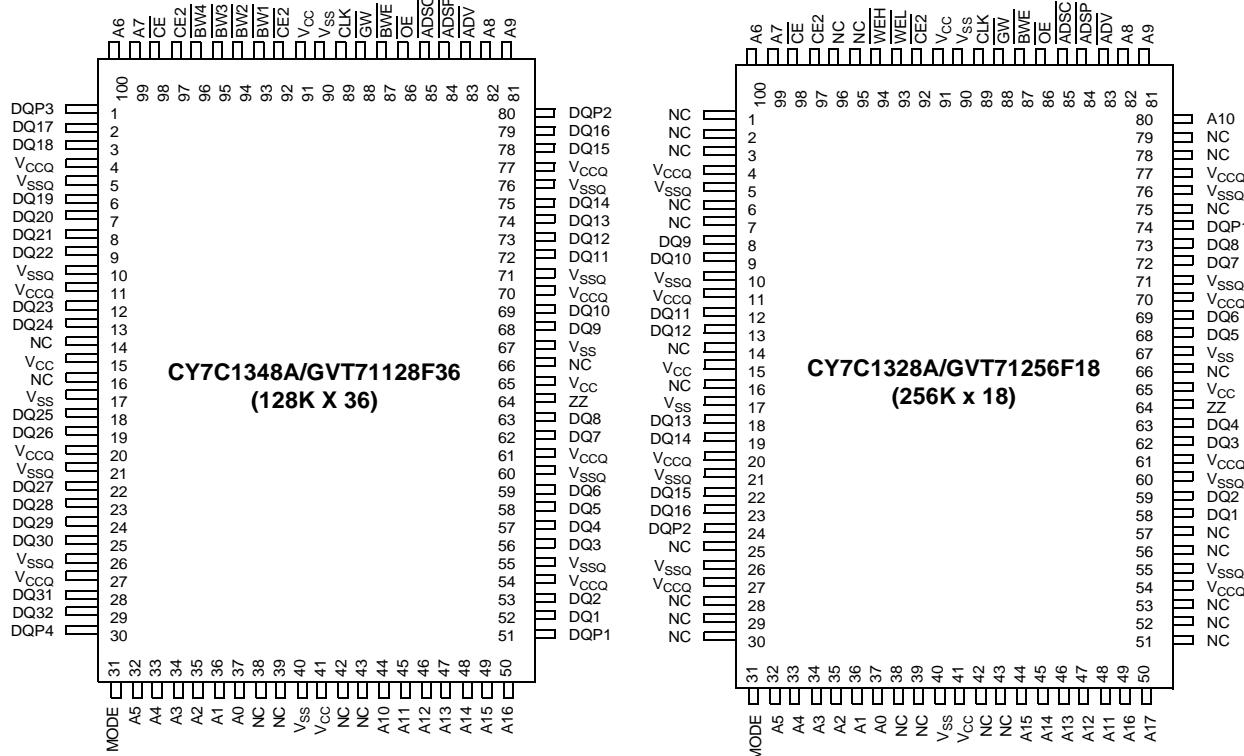
**Functional Block Diagram—128Kx36<sup>[1]</sup>**

**Functional Block Diagram—256Kx18<sup>[1]</sup>**

**Note:**

1. The Functional Block Diagram illustrates simplified device operation. See Truth Table, pin descriptions and timing diagrams for detailed information.



## Pin Configurations

**100-Pin TQFP  
Top View**



## Pin Descriptions

| Name   | Type               | Description   |
|--|--------------------|---|
| A0<br>A1<br>A2–A17<br>(A17 for X18)                  | Input-Synchronous  | Addresses: These inputs are registered and must meet the set-up and hold times around the rising edge of CLK. The burst counter generates internal addresses associated with A0 and A1, during burst cycle and wait cycle.  |
| <u>BW1</u><br><u>BW2</u><br><u>BW3</u><br><u>BW4</u> | Input-Synchronous  | Byte Write Enables: A byte write enable is LOW for a WRITE cycle and HIGH for a READ cycle. BW1 controls DQ1–DQ8 and DQP1. BW2 controls DQ9–DQ16 and DQP2. BW3 controls DQ17–DQ24 and DQP3. BW4 controls DQ25–DQ32 and DQP4. Data I/O are high impedance if either of these inputs are LOW, conditioned by BWE being LOW. BW1 is equal to WEL and BW2 is equal to WEH for X18 device. |
| <u>BWE</u>   | Input-Synchronous  | Write Enable: This active LOW input gates byte write operations and must meet the set-up and hold times around the rising edge of CLK.  |
| <u>GW</u>  | Input-Synchronous  | Global Write: This active LOW input allows a full 38-bit (18-bit for X18 device) WRITE to occur independent of the <u>BWE</u> and <u>BWn</u> lines and must meet the set-up and hold times around the rising edge of CLK.   |
| CLK  | Input-Synchronous  | Clock: This signal registers the addresses, data, chip enables, write control and burst control inputs on its rising edge. All synchronous inputs must meet set-up and hold times around the clock's rising edge.   |
| <u>CE</u>  | Input-Synchronous  | Chip Enable: This active LOW input is used to enable the device and to gate <u>ADSP</u> .   |
| <u>CE2</u>   | Input-Synchronous  | Chip Enable: This active LOW input is used to enable the device.  |
| CE2  | Input-Synchronous  | Chip Enable: This active HIGH input is used to enable the device.   |
| <u>OE</u>  | Input              | Output Enable: This active LOW asynchronous input enables the data output drivers.  |
| <u>ADV</u>   | Input-Synchronous  | Address Advance: This active LOW input is used to control the internal burst counter. A HIGH on this pin generates wait cycle (no address advance).   |
| <u>ADSP</u>  | Input-Synchronous  | Address Status Processor: This active LOW input, along with <u>CE</u> being LOW, causes a new external address to be registered and a READ cycle is initiated using the new address.  |
| <u>ADSC</u>  | Input-Synchronous  | Address Status Controller: This active LOW input causes device to be deselected or selected along with new external address to be registered. A READ or WRITE cycle is initiated depending upon write control inputs.   |
| MODE   | Input-Static       | Mode: This input selects the burst sequence. A LOW on this pin selects Linear Burst. A NC or HIGH on this pin selects Interleaved Burst.  |
| ZZ   | Input-Asynchronous | Snooze: This active HIGH input puts the device in low power consumption standby mode. For normal operation, this input has to be either LOW or NC (No Connect).   |
| DQ1–8<br>DQ9–16<br>DQ17–24<br>DQ25–32                | Input/Output       | Data Inputs/Outputs: Byte one is DQ1–DQ8. Byte two is DQ9–DQ16. Byte three is DQ17–DQ24. Byte four is DQ25–DQ32. Input data must meet set-up and hold times around the rising edge of CLK. X18 only has two bytes (Byte one and Byte two).  |
| DQP1–DQP4  | Input/Output       | Parity Inputs/Outputs: DQP1 is parity bit for DQ1–DQ8 and DQP2 is parity bit for DQ9–DQ16. DQP3 is parity bit for DQ17–DQ24 and DQP4 is parity bit for DQ25–DQ32.   |
| V <sub>CC</sub>                                      | Supply             | Power Supply: +3.3V –5% and +10%.   |
| V <sub>SS</sub>                                      | Ground             | Ground: GND.  |
| V <sub>CCQ</sub>                                     | I/O Supply         | Output Buffer Supply: +2.5V (from 2.375V to V <sub>CC</sub> ).  |
| V <sub>SSQ</sub>                                     | I/O Ground         | Output Buffer Ground: GND.  |
| NC   | -                  | No Connect: These signals are not internally connected. User can connect them to V <sub>CC</sub> , V <sub>SS</sub> , or any signal. They can be left unconnected as floating.   |



**Burst Address Table (MODE = NC/V<sub>CC</sub>)**

| First Address (external) | Second Address (internal) | Third Address (internal) | Fourth Address (internal) |
|--------------------------|---------------------------|--------------------------|---------------------------|
| A...A00                  | A...A01                   | A...A10                  | A...A11                   |
| A...A01                  | A...A00                   | A...A11                  | A...A10                   |
| A...A10                  | A...A11                   | A...A00                  | A...A01                   |
| A...A11                  | A...A10                   | A...A01                  | A...A00                   |

**Burst Address Table (MODE = GND)**

| First Address (external) | Second Address (internal) | Third Address (internal) | Fourth Address (internal) |
|--------------------------|---------------------------|--------------------------|---------------------------|
| A...A00                  | A...A01                   | A...A10                  | A...A11                   |
| A...A01                  | A...A00                   | A...A11                  | A...A00                   |
| A...A10                  | A...A11                   | A...A00                  | A...A01                   |
| A...A11                  | A...A00                   | A...A01                  | A...A10                   |

**Truth Table**<sup>[2, 3, 4, 5, 6, 7, 8]</sup>

| Operation                    | Address Used | $\overline{CE}$ | $\overline{CE2}$ | CE2 | $\overline{ADSP}$ | $\overline{ADSC}$ | $\overline{ADV}$ | $\overline{WRITE}$ | $\overline{OE}$ | CLK | DQ     |
|------------------------------|--------------|-----------------|------------------|-----|-------------------|-------------------|------------------|--------------------|-----------------|-----|--------|
| Deselected Cycle, Power Down | None         | H               | X                | X   | X                 | L                 | X                | X                  | X               | L-H | High-Z |
| Deselected Cycle, Power Down | None         | L               | X                | L   | L                 | X                 | X                | X                  | X               | L-H | High-Z |
| Deselected Cycle, Power Down | None         | L               | H                | X   | L                 | X                 | X                | X                  | X               | L-H | High-Z |
| Deselected Cycle, Power Down | None         | L               | X                | L   | H                 | L                 | X                | X                  | X               | L-H | High-Z |
| Deselected Cycle, Power Down | None         | L               | H                | X   | H                 | L                 | X                | X                  | X               | L-H | High-Z |
| READ Cycle, Begin Burst      | External     | L               | L                | H   | L                 | X                 | X                | X                  | L               | L-H | Q      |
| READ Cycle, Begin Burst      | External     | L               | L                | H   | L                 | X                 | X                | X                  | H               | L-H | High-Z |
| WRITE Cycle, Begin Burst     | External     | L               | L                | H   | H                 | L                 | X                | L                  | X               | L-H | D      |
| READ Cycle, Begin Burst      | External     | L               | L                | H   | H                 | L                 | X                | H                  | L               | L-H | Q      |
| READ Cycle, Begin Burst      | External     | L               | L                | H   | H                 | L                 | X                | H                  | H               | L-H | High-Z |
| READ Cycle, Continue Burst   | Next         | X               | X                | X   | H                 | H                 | L                | H                  | L               | L-H | Q      |
| READ Cycle, Continue Burst   | Next         | X               | X                | X   | H                 | H                 | L                | H                  | H               | L-H | High-Z |
| READ Cycle, Continue Burst   | Next         | H               | X                | X   | X                 | H                 | L                | H                  | L               | L-H | Q      |
| READ Cycle, Continue Burst   | Next         | H               | X                | X   | X                 | H                 | L                | H                  | H               | L-H | High-Z |
| WRITE Cycle, Continue Burst  | Next         | X               | X                | X   | H                 | H                 | L                | L                  | X               | L-H | D      |
| WRITE Cycle, Continue Burst  | Next         | H               | X                | X   | X                 | H                 | L                | L                  | X               | L-H | D      |
| READ Cycle, Suspend Burst    | Current      | X               | X                | X   | H                 | H                 | H                | H                  | L               | L-H | Q      |
| READ Cycle, Suspend Burst    | Current      | X               | X                | X   | H                 | H                 | H                | H                  | H               | L-H | High-Z |
| READ Cycle, Suspend Burst    | Current      | H               | X                | X   | X                 | H                 | H                | H                  | L               | L-H | Q      |
| READ Cycle, Suspend Burst    | Current      | H               | X                | X   | X                 | H                 | H                | H                  | H               | L-H | High-Z |
| WRITE Cycle, Suspend Burst   | Current      | X               | X                | X   | H                 | H                 | H                | L                  | X               | L-H | D      |
| WRITE Cycle, Suspend Burst   | Current      | H               | X                | X   | X                 | H                 | H                | L                  | X               | L-H | D      |

**Notes:**

2. X = "Don't Care." H = logic HIGH, L = logic LOW.  
 $\overline{WRITE} = L$  means  $[BWE + BWa \cdot BWb] \cdot GW$  equals LOW.  $\overline{WRITE} = H$  means  $[\overline{BWE} + \overline{BWa} \cdot \overline{BWb}] \cdot GW$  equals HIGH.
3. BWa enables write to DQa. BWb enables write to DQb.
4. All inputs except OE must meet set-up and hold times around the rising edge (LOW to HIGH) of CLK.
5. Suspending burst generates wait cycle.
6. For a write operation following a read operation,  $\overline{OE}$  must be HIGH before the input data required setup time plus High-Z time for  $\overline{OE}$  and staying HIGH throughout the input data hold time.
7. This device contains circuitry that will ensure the outputs will be in High-Z during power-up.
8. ADSP LOW along with chip being selected always initiates a READ cycle at the L-H edge of CLK. A WRITE cycle can be performed by setting  $\overline{WRITE}$  LOW for the CLK L-H edge of the subsequent wait cycle. Refer to WRITE timing diagram for clarification.



### Partial Truth Table for READ/WRITE

| Function        | <b>GW</b> | <b>BWE</b> | <b>BW1</b> | <b>BW2</b> | <b>BW3</b> | <b>BW4</b> |
|-----------------|-----------|------------|------------|------------|------------|------------|
| READ            | H         | H          | X          | X          | X          | X          |
| READ            | H         | L          | H          | H          | H          | H          |
| WRITE one byte  | H         | L          | L          | H          | H          | H          |
| WRITE all bytes | H         | L          | L          | L          | L          | L          |
| WRITE all bytes | L         | X          | X          | X          | X          | X          |

### Maximum Ratings

(Above which the useful life may be impaired. For user guidelines, not tested.)

Voltage on V<sub>CC</sub> Supply Relative to V<sub>SS</sub> ..... -0.5V to +4.6V  
V<sub>IN</sub> ..... -0.5V to V<sub>CC</sub>+0.5V  
Storage Temperature (plastic) ..... -55°C to +150°  
Junction Temperature ..... +150°

#### Note:

9. T<sub>A</sub> is the case temperature.
10. Please refer to waveform (c)
11. Power Supply ramp-up should be monotonic.

Power Dissipation..... 1.0W

Short Circuit Output Current..... 50 mA

### Operating Range

| Range | Ambient Temperature <sup>[9]</sup> | V <sub>CC</sub> <sup>[10,11]</sup> |
|-------|------------------------------------|------------------------------------|
| Com'l | 0°C to +70°C                       | 3.3V -5%/+10%                      |



### Electrical Characteristics Over the Operating Range

| Parameter | Description                                      | Test Conditions                                   | Min.  | Max.           | Unit    |
|-----------|--|---|-------|----------------|---------|
| $V_{IHD}$ | Input High (Logic 1) Voltage <sup>[12, 13]</sup> | Data Inputs (DQxx)                                | 1.7   | $V_{CC} + 0.3$ | V       |
| $V_{IH}$  |  | All Other Inputs                                  | 1.7   | 4.6            | V       |
| $V_{IL}$  | Input Low (Logic 0) Voltage <sup>[12, 13]</sup>  |   | -0.3  | 0.7            | V       |
| $I_{L_O}$ | Input Leakage Current <sup>[14]</sup>            | $0V \leq V_{IN} \leq V_{CC}$                      | -2    | 2              | $\mu A$ |
| $I_{O_L}$ | Output Leakage Current                           | Output(s) disabled, $0V \leq V_{OUT} \leq V_{CC}$ | -2    | 2              | $\mu A$ |
| $V_{OH}$  | Output High Voltage <sup>[12, 15]</sup>          | $I_{OH} = -2.0$ mA                                | 1.7   |                | V       |
| $V_{OL}$  | Output Low Voltage <sup>[12, 15]</sup>           | $I_{OL} = 2.0$ mA                                 |       | 0.7            | V       |
| $V_{CC}$  | Supply Voltage <sup>[12]</sup>                   |   | 3.135 | 3.6            | V       |
| $V_{CCQ}$ | I/O Supply Voltage <sup>[12]</sup>               |   | 2.375 | $V_{CC}$       | V       |

| Parameter | Description  | Conditions   | Typ. | -4  | -4.4 | -5  | -6  | Unit |
|-----------|--|--|------|-----|------|-----|-----|------|
| $I_{CC}$  | Power Supply Current:<br>Operating <sup>[16, 17, 18]</sup> | Device selected; all inputs $\leq V_{IL}$ or $\geq V_{IH}$ ; cycle time $\geq t_{KC}$ min.; $V_{CC} = \text{Max.}$ ; outputs open        | 150  | 425 | 400  | 375 | 350 | mA   |
| $I_{SB2}$ | CMOS Standby <sup>[17, 18]</sup>                           | Device deselected; $V_{CC} = \text{Max.}$ ; all inputs $\leq V_{SS} + 0.2$ or $\geq V_{CC} - 0.2$ ; all inputs static; CLK frequency = 0 | 5    | 10  | 10   | 10  | 10  | mA   |
| $I_{SB3}$ | TTL Standby <sup>[17, 18]</sup>                            | Device deselected; all inputs $\leq V_{IL}$ or $\geq V_{IH}$ ; all inputs static; $V_{CC} = \text{Max.}$ ; CLK frequency = 0             | 10   | 20  | 20   | 20  | 20  | mA   |
| $I_{SB4}$ | Clock Running <sup>[17, 18]</sup>                          | Device deselected; all inputs $\leq V_{IL}$ or $\geq V_{IH}$ ; $V_{CC} = \text{Max.}$ ; CLK cycle time $\geq t_{KC}$ min.                | 40   | 90  | 80   | 70  | 60  | mA   |

### Capacitance<sup>[19]</sup>

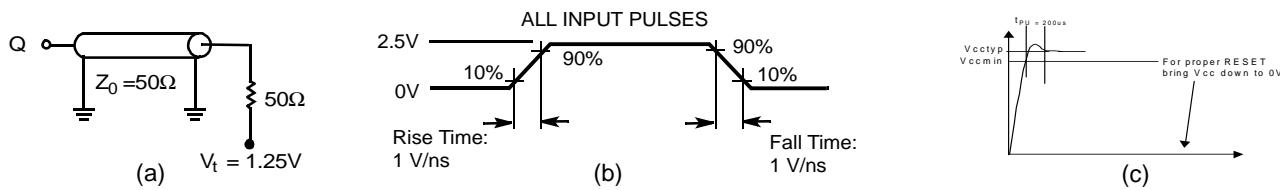
| Parameter | Description                   | Test Conditions                                      | Typ. | Max. | Unit |
|-----------|-------------------------------|--|------|------|------|
| $C_I$     | Input Capacitance             | $T_A = 25^\circ C$ , $f = 1$ MHz,<br>$V_{CC} = 3.3V$ | 5    | 7    | pF   |
| $C_O$     | Input/Output Capacitance (DQ) |  | 7    | 8    | pF   |

### Thermal Resistance

| Description                              | Test Conditions   | Symbol        | TQFP Typ. | Unit |
|--|---|---------------|-----------|------|
| Thermal Resistance (Junction to Ambient) | Still Air, soldered on a 4.25 x 1.125 inch, 4-layer PCB | $\Theta_{JA}$ | 25        | °C/W |
| Thermal Resistance (Junction to Case)    |   | $\Theta_{JC}$ | 9         | °C/W |

Note:

12. All voltages referenced to  $V_{SS}$  (GND).
13. Overshoot:  $V_{IH} \leq +6.0V$  for  $t \leq t_{KC}/2$ .  
Undershoot:  $V_{IL} \leq -2.0V$  for  $t \leq t_{KC}/2$
14. MODE pin has an internal pull-up and ZZ pin has an internal pull-down. These two pins exhibit an input leakage current of  $\pm 30 \mu A$ .
15. AC I/O curves are available upon request.
16.  $I_{CC}$  is given with no output current.  $I_{CC}$  increases with greater output loading and faster cycle times.
17. "Device Deselected" means the device is in Power-Down mode as defined in the truth table. "Device Selected" means the device is active.
18. Typical values are measured at 3.3V, 25°C, and 8.5-ns cycle time.
19. This parameter is sampled.

**AC Test Loads and Waveforms<sup>[20]</sup>**

**Switching Characteristics Over the Operating Range<sup>[21]</sup>**

| Parameter           | Description                                       | -3<br>166 MHz |      | -4<br>150 MHz |      | -5<br>133 MHz |      | -6<br>117 MHz |      | Unit |
|---------------------|---|---------------|------|---------------|------|---------------|------|---------------|------|------|
|                     |   | Min.          | Max. | Min.          | Max. | Min.          | Max. | Min.          | Max. |      |
| <b>Clock</b>        |   |               |      |               |      |               |      |               |      |      |
| $t_{KC}$            | Clock Cycle Time                                  | 6.0           |      | 6.7           |      | 7.5           |      | 8.5           |      | ns   |
| $t_{KH}$            | Clock HIGH Time                                   | 2.4           |      | 2.6           |      | 2.8           |      | 3.4           |      | ns   |
| $t_{KL}$            | Clock LOW Time                                    | 2.4           |      | 2.6           |      | 2.8           |      | 3.4           |      | ns   |
| <b>Output Times</b> |   |               |      |               |      |               |      |               |      |      |
| $t_{KQ}$            | Clock to Output Valid                             |               | 3.5  |               | 3.8  |               | 4.0  |               | 4.0  | ns   |
| $t_{KQX}$           | Clock to Output Invalid                           | 1.5           |      | 1.5           |      | 1.5           |      | 1.5           |      | ns   |
| $t_{KQLZ}$          | Clock to Output in Low-Z <sup>[19, 22, 23]</sup>  | 0             |      | 0             |      | 0             |      | 0             |      | ns   |
| $t_{KQHZ}$          | Clock to Output in High-Z <sup>[19, 22, 23]</sup> | 1.5           | 6.0  | 1.5           | 6.7  | 1.5           | 7.5  | 1.5           | 8.5  | ns   |
| $t_{OEQ}$           | OE to Output Valid <sup>[24]</sup>                |               | 3.5  |               | 3.5  |               | 3.8  |               | 3.8  | ns   |
| $t_{OELZ}$          | OE to Output in Low-Z <sup>[19, 22, 23]</sup>     | 0             |      | 0             |      | 0             |      | 0             |      | ns   |
| $t_{OEHZ}$          | OE to Output in High-Z <sup>[19, 22, 23]</sup>    |               | 3.5  |               | 3.5  |               | 3.8  |               | 3.8  | ns   |
| <b>Set-up Times</b> |   |               |      |               |      |               |      |               |      |      |
| $t_S$               | Address, Controls, and Data In <sup>[25]</sup>    | 1.5           |      | 1.5           |      | 1.5           |      | 2.0           |      | ns   |
| <b>Hold Times</b>   |   |               |      |               |      |               |      |               |      |      |
| $t_H$               | Address, Controls, and Data In <sup>[25]</sup>    | 0.5           |      | 0.5           |      | 0.5           |      | 0.5           |      | ns   |

**Typical Output Buffer Characteristics**

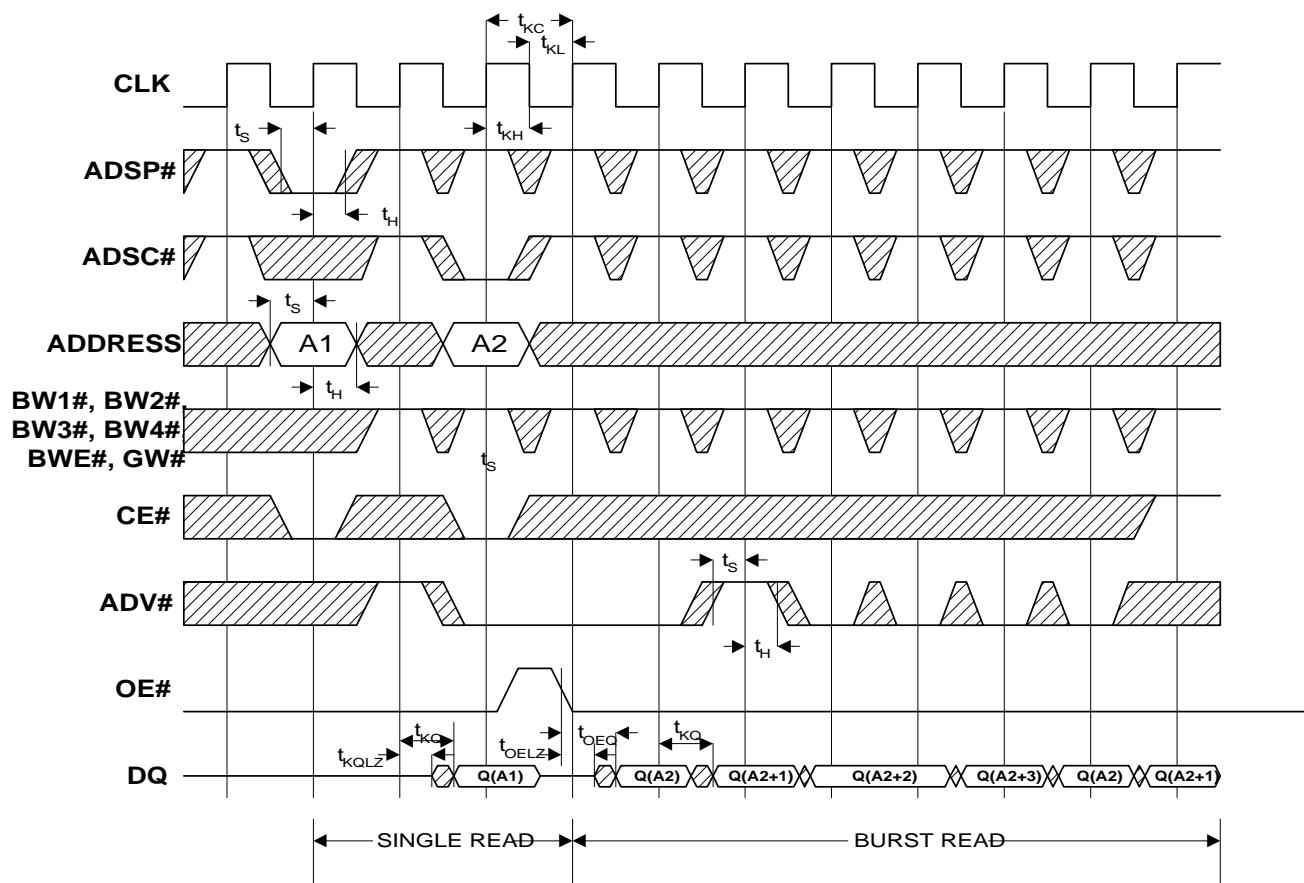
| Output High Voltage | Pull-Up Current    |                    | Output Low Voltage | Pull-Down Current  |                    |
|---------------------|--------------------|--------------------|--------------------|--------------------|--------------------|
| $V_{OH}$ (V)        | $I_{OH}$ (mA) Min. | $I_{OH}$ (mA) Max. | $V_{OL}$ (V)       | $I_{OL}$ (mA) Min. | $I_{OL}$ (mA) Max. |
| -0.5                | -38                | -105               | -0.5               | 0                  | 0                  |
| 0                   | -38                | -105               | 0                  | 0                  | 0                  |
| 0.8                 | -38                | -105               | 0.4                | 10                 | 20                 |
| 1.25                | -26                | -83                | 0.8                | 20                 | 40                 |
| 1.5                 | -20                | -70                | 1.25               | 31                 | 63                 |
| 2.3                 | 0                  | -30                | 1.6                | 40                 | 80                 |
| 2.7                 | 0                  | -10                | 2.8                | 40                 | 80                 |
| 2.9                 | 0                  | 0                  | 3.2                | 40                 | 80                 |
| 3.4                 | 0                  | 0                  | 3.4                | 40                 | 80                 |

**Notes:**

20. Overshoot:  $VIH(AC) < VDD + 1.5V$  for  $t < t_{TCYC}/2$ ; undershoot:  $VIL(AC) < 0.5V$  for  $t < t_{TCYC}/2$ ; power-up:  $VIH < 2.6V$  and  $VDD < 2.4V$  and  $VDDQ < 1.4V$  for  $t < 200$  ms.
21. Test conditions as specified with the output loading as shown in part (a) of AC Test Loads unless otherwise noted.
22. Output loading is specified with  $C_L = 5 \text{ pF}$  as in AC Test Loads.
23. At any given temperature and voltage condition,  $t_{KQHZ}$  is less than  $t_{KQLZ}$  and  $t_{OEHZ}$  is less than  $t_{OELZ}$ .
24. OE is a "Don't Care" when a byte write enable is sampled LOW.
25. This is a synchronous device. All synchronous inputs must meet specified set-up and hold time, except for "Don't Care" as defined in the truth table.

## Switching Waveforms

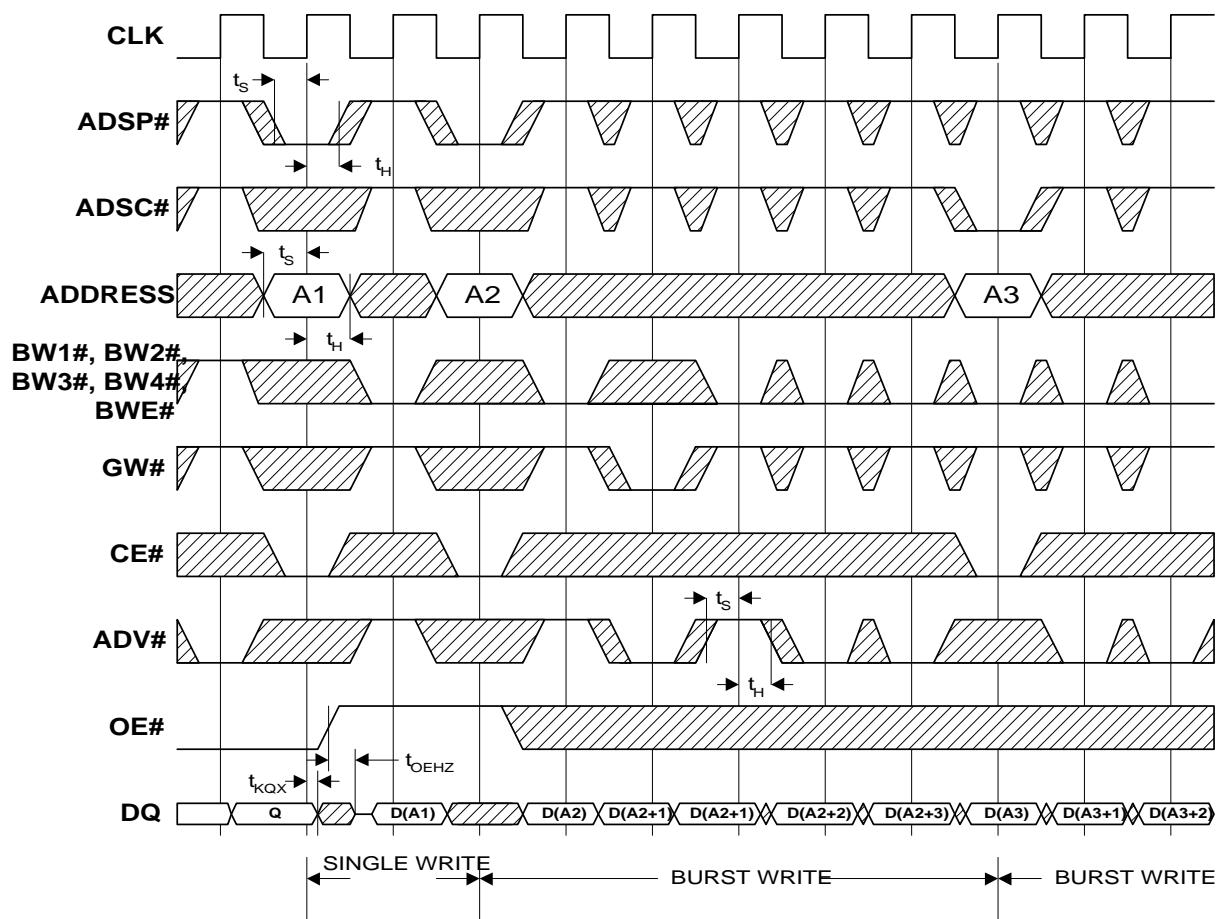
Read Timing<sup>[26, 27]</sup>



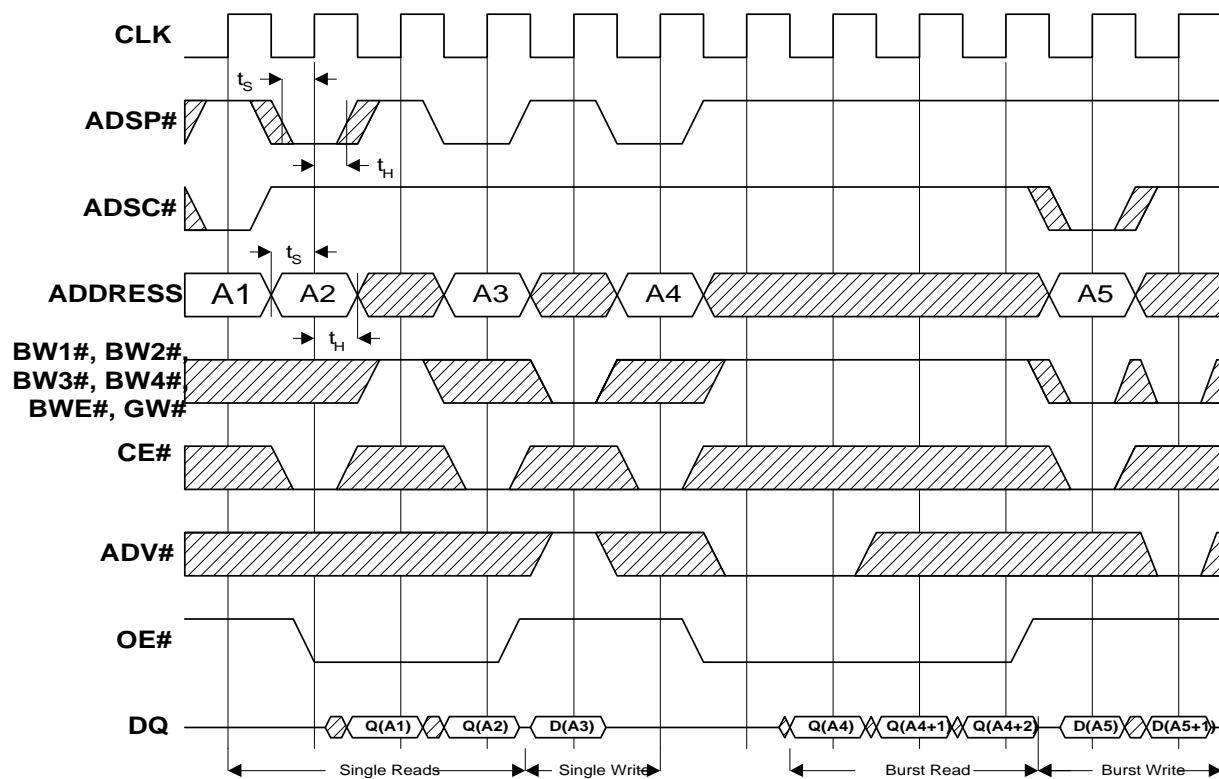
**Notes:**

26.  $\overline{CE}$  active in this timing diagram means that all chip enables  $\overline{CE}_1$ ,  $\overline{CE}_2$ , and  $\overline{CE}_3$  are active.
27. For X18 product, there are only BW1 (i.e., WEL) and BW2 (i.e., WEH) for byte write control.

**Switching Waveforms** (continued)

**Write Timing**<sup>[26, 27]</sup>


**Switching Waveforms** (continued)

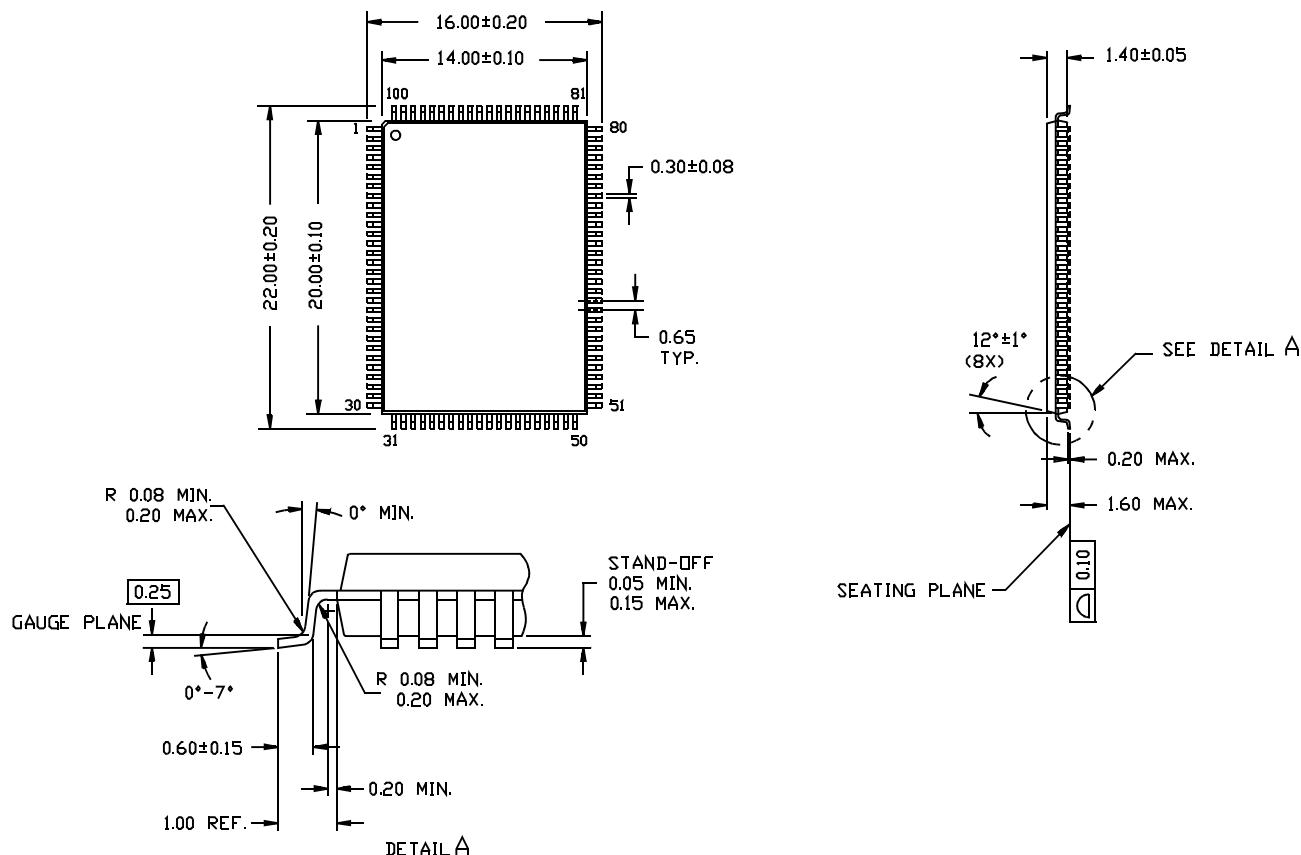
**Read/Write Timing**<sup>[26, 27]</sup>

**Ordering Information**

| Speed (MHz) | Ordering Code                  | Package Name | Package Type                                  | Operating Range |
|-------------|--------------------------------|--------------|---|-----------------|
| 166         | CY7C1328A-166AC/GVT71256F18T-3 | A101         | 100-Lead 14 x 20 x 1.4 mm Thin Quad Flat Pack | Commercial      |
| 150         | CY7C1328A-150AC/GVT71256F18T-4 | A101         | 100-Lead 14 x 20 x 1.4 mm Thin Quad Flat Pack |                 |
| 133         | CY7C1328A-133AC/GVT71256F18T-5 | A101         | 100-Lead 14 x 20 x 1.4 mm Thin Quad Flat Pack |                 |
| 117         | CY7C1328A-117AC/GVT71256F18T-6 | A101         | 100-Lead 14 x 20 x 1.4 mm Thin Quad Flat Pack |                 |
| 166         | CY7C1348A-166AC/GVT71128F36T-3 | A101         | 100-Lead 14 x 20 x 1.4 mm Thin Quad Flat Pack |                 |
| 150         | CY7C1348A-150AC/GVT71128F36T-4 | A101         | 100-Lead 14 x 20 x 1.4 mm Thin Quad Flat Pack |                 |
| 133         | CY7C1348A-133AC/GVT71128F36T-5 | A101         | 100-Lead 14 x 20 x 1.4 mm Thin Quad Flat Pack |                 |
| 117         | CY7C1348A-117AC/GVT71128F36T-6 | A101         | 100-Lead 14 x 20 x 1.4 mm Thin Quad Flat Pack |                 |

## Package Diagram

**100-Pin Thin Plastic Quad Flatpack (14 x 20 x 1.4 mm) A101**

DIMENSIONS ARE IN MILLIMETERS.



51-85050-A



**CY7C1328A/GVT71256F18  
CY7C1348A/GVT71128F36**

**Document Title:** CY7C1328A/GVT71256F18, CY7C1348A/GVT71128F36 128K x 36/256K x 18 Synchronous-Pipelined Cache RAM  
**Document Number:** 38-05152

| REV. | ECN NO. | Issue Date | Orig. of Change | Description of Change   |
|------|---------|------------|-----------------|---|
| **   | 109896  | 09/22/01   | SZV             | Change from Spec number: 38-00999 to 38-05152                 |
| *A   | 111423  | 01/31/02   | GLC             | Removed preliminary from data sheet.                          |
| *B   | 123138  | 01/20/03   | RBI             | Add power up requirements to operating conditions information |